

Powered-off Protection, 0.85 Ω , 1.8 V to 5.5 V, SPDT Analog Switch (2:1 Multiplexer)

DESCRIPTION

The DG2001E is a high performance single-pole, double-throw (SPDT) analog switch designed for 1.8 V to 5.5 V operation with a single power rail.

Fabricated with high density CMOS technology, the device achieves low on resistance of 0.85 Ω at a 5 V power supply, low power consumption, and fast switching speeds.

The DG2001E can handle both analog and digital signals and permits signals with amplitudes of up to V_{+} to be transmitted in either direction. Its control logic inputs can go over V_{+} up to 5.5 V. The control logic input high threshold is guaranteed as low as 1.8 V over the power supply range up to 5.5 V. It features break before make switching performance.

A powered-off protection circuit is built into the switch to prevent an abnormal current flow from COM pin to V_{+} during the power-down condition. Each output pin can withstand greater than 7 kV (human body model).

Operation temperature is specified from -40 $^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$. The DG2001E is available in TSOP-6 package.

FEATURES

- Low switch on-resistance (0.85 Ω)
- 1.8 V to 5.5 V single supply operation
- Isolation in powered-off mode
- Guaranteed 1.8 V logic high
- Control logic inputs can go over V_{+}
- Low charge injection (8 pC)
- Break before make switching
- Latch-up performance exceeds 300 mA per JESD 78
- ESD tested
 - 7000 V human body model (JS-001)
 - 1000 V charge device model (JS-002)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

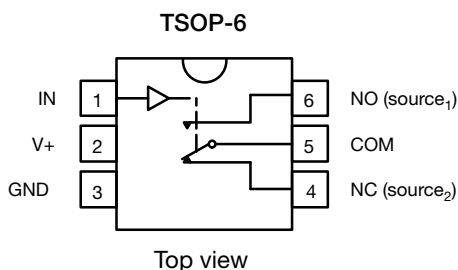


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COMPLIANT
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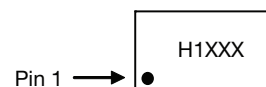
APPLICATIONS

- Consumer and computing
- Portable instrumentation
- Medical equipment
- Battery operated systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Device marking: H1



Device marking: H1XXX
XXX = date / lot traceability code

TRUTH TABLE		
LOGIC	NC	NO
0	On	Off
1	Off	On

ORDERING INFORMATION		
TEMP RANGE	PACKAGE	PART NUMBER
-40 $^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$	TSOP-6	DG2001EDV-T1-GE3

**ABSOLUTE MAXIMUM RATINGS** ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)

PARAMETER		LIMIT	UNIT
V_+ , COM, NC, NO, IN reference to GND		-0.3 to 6	V
Continuous current (any terminal)		± 50	mA
Peak current (pulsed at 1 ms, 10 % duty cycle)		± 200	
Storage temperature (D suffix)		-65 to +125	$^{\circ}\text{C}$
Power dissipation (packages) ^a	TSOP-6 ^b	570	mW
ESD / HBM	JS-001	7000	V
ESD / CDM	JS-002	1000	
Latch up	Per JEDEC78 with 1.5 x voltage clamp	300	mA

Notes

- a. All leads welded or soldered to PC board
b. Derate 7 mW/ $^{\circ}\text{C}$ above 25 $^{\circ}\text{C}$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

SPECIFICATIONS ($V_+ = 5\text{ V}$)

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 5 V, ± 10 % VIN = 0.8 V or 2.4 V ^e	TEMP. ^a	LIMITS -40 °C to +85 °C			UNIT
				MIN. ^b	TYP. ^c	MAX. ^b	
Analog Switch							
Analog signal range ^d	VNO, VNC VCOM		Full	0	-	V+	V
On-resistance	RON	V+ = 4.5 V VCOM = 3 V, INO, INC = 10 mA	Room	-	0.85	1.6	Ω
			Full	-	-	1.8	
RON flatness ^d	RON Flatness	V+ = 4.5 V VCOM = 0 V to V+, INO, INC = 10 mA	Room	-	0.3	-	
Switch off leakage current ^g	INO(off) INC(off)	V+ = 5.5 V VNO, VNC = 1 V / 4.5 V, VCOM = 4.5 V / 1 V	Room	-5	-	5	nA
			Full	-30	-	30	
	ICOM(off)		Room	-5	-	5	
			Full	-30	-	30	
Channel-on leakage current ^g	ICOM(on)	V+ = 5.5 V VNO, VNC = VCOM = 1 V / 4.5 V	Room	-5	-	5	
			Full	-30	-	30	
Power down leakage	ICOM(PD)	V+ = 0 V, VCOM = 4.5 V, VIN = GND	Full ^d	-	-	1	μA
Digital Control							
Input high voltage	VINH		Full	2.4	-	-	V
Input low voltage	VINL		Full	-	-	0.8	
Input capacitance	CIN		Full	-	3	-	pF
Input current	IINL or IINH	VIN = 0 V or V+	Full	-1	-	1	μA
Dynamic Characteristics							
Turn-on time	tON	VNO or VNC = 3 V, RL = 300 Ω, CL = 35 pF	Room	-	15	32	ns
			Full	-	-	35	
Turn-off time	tOFF		Room	-	6	26	
			Full	-	-	31	
Break-before-make time	td		Room	1	4	-	
Charge injection ^d	QINJ	CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω	Room	-	8	-	pC
Off-isolation ^d	OIRR	RL = 50 Ω, CL = 5 pF, f = 1 MHz	Room	-	-63	-	dB
Crosstalk ^d	XTALK		Room	-	-63	-	
Source-off capacitance ^d	CNO(off) CNC(off)	VIN = 0 V or V+, f = 1 MHz	Room	-	16	-	pF
Channel-on capacitance ^d	CON		Room	-	53	-	
Power Supply							
Power supply current	I+	VIN = 0 V or V+	Full	-	0.0003	1	μA



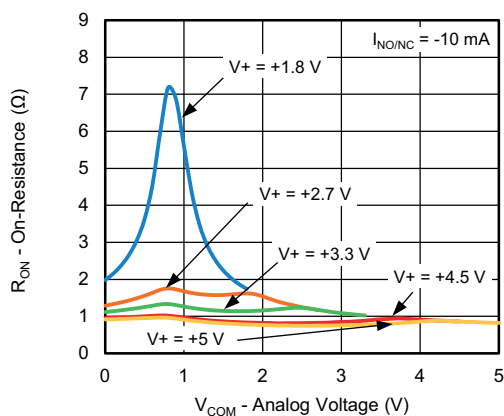
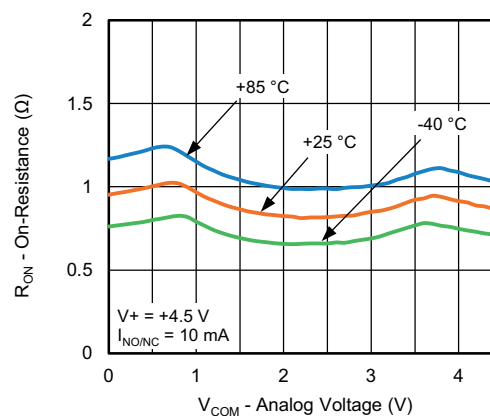
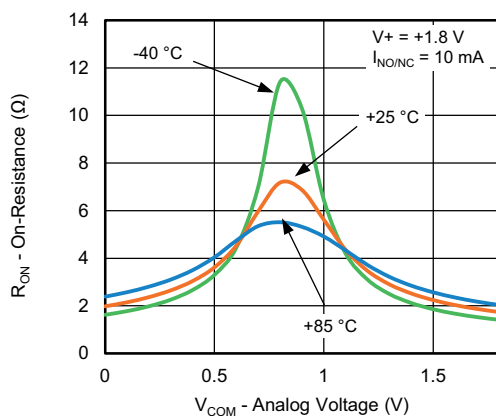
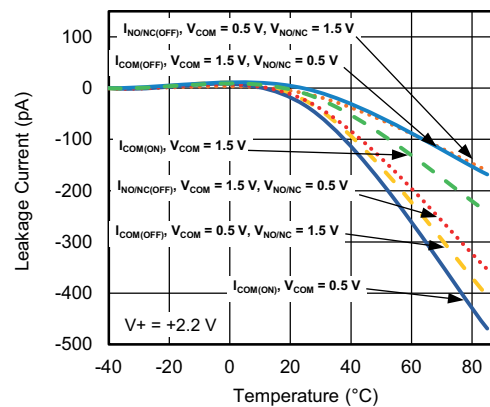
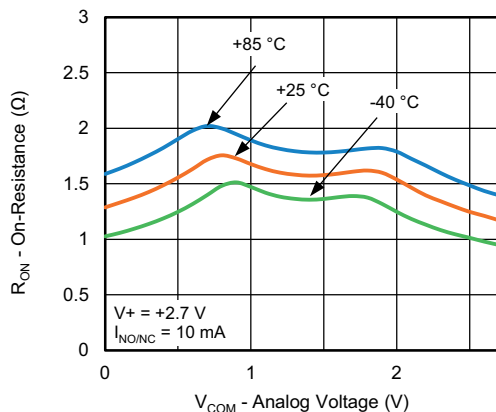
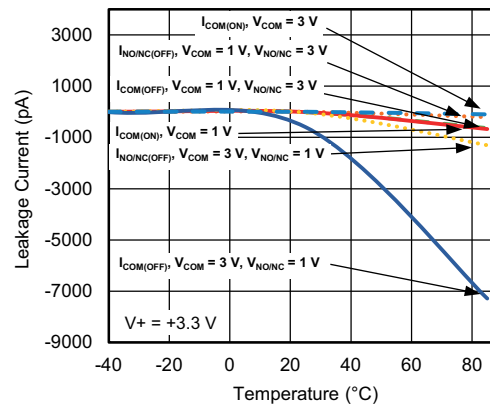
SPECIFICATIONS (V+ = 3 V)							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 3 V, ± 10 % VIN = 0.4 V or 2 V ^e	TEMP. ^a	LIMITS -40 °C to +85 °C			UNIT
				MIN. ^b	TYP. ^c	MAX. ^b	
Analog Switch							
Analog signal range ^d	VNO, VNC, VCOM		Full	0	-	V+	V
On-resistance	RON	V+ = 2.7 V VCOM = 1.5 V, INO, INC = 10 mA	Room	-	1.6	2.2	Ω
			Full	-	-	2.6	
RON flatness ^d	RON Flatness	V+ = 2.7 V VCOM = 0 V to V+, INO, INC = 10 mA	Room	-	0.6	-	
Switch off leakage current ^g	INO(off) INC(off)	V+ = 3.3 V VNO, VNC = 1 V / 3 V, VCOM = 3 V / 1 V	Room	-5	-	5	nA
			Full	-15	-	15	
	ICOM(off)		Room	-5	-	5	
			Full	-15	-	15	
Channel-on leakage current ^g	ICOM(on)	V+ = 3.3 V VNO, VNC = VCOM = 1 V / 3 V	Room	-5	-	5	
			Full	-15	-	15	
Digital Control							
Input high voltage	VINH		Full	2	-	-	V
Input low voltage	VINL		Full	-	-	0.4	
Input capacitance	CIN		Full	-	-	-	pF
Input current	IINL or IINH	VIN = 0 V or V+	Full	-1	-	1	μA
Dynamic Characteristics							
Turn-on time	tON	VNO or VNC = 2 V, RL = 300 Ω, CL = 35 pF	Room	-	21	42	ns
			Full	-	-	47	
Turn-off time	tOFF		Room	-	9	32	
			Full	-	-	35	
Break-before-make time	td		Room	1	7	-	
Charge injection ^d	QINJ	CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω	Room	-	6	-	pC
Off-isolation ^d	OIRR	RL = 50 Ω, CL = 5 pF, f = 1 MHz	Room	-	-63	-	dB
Crosstalk ^d	XTALK		Room	-	-63	-	
NO, NC off capacitance ^d	CNO(off) CNC(off)	VIN = 0 V or V+, f = 1 MHz	Room	-	16	-	pF
Channel-on capacitance ^d	CON		Room	-	54	-	
Power Supply							
Power supply current	I+	VIN = 0 V or V+	Full	-	0.00002	1	μA



SPECIFICATIONS (V+ = 2 V)								
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 2 V, ± 10 % VIN = 0.4 V or 1.6 V ^e	TEMP. ^a	LIMITS -40 °C to +85 °C			UNIT	
				MIN. ^b	TYP. ^c	MAX. ^b		
Analog Switch								
Analog signal range ^d	VNO, VNC VCOM		Full	0	-	V+	V	
On-resistance	RON	V+ = 1.8 V VCOM = 1 V, INO, INC = 10 mA	Room	-	6	8	Ω	
			Full	-	-	10		
RON flatness ^d	RON Flatness	V+ = 1.8 V VCOM = 0 V to V+, INO, INC = 10 mA	Room	-	6	-		
Switch off leakage current ^g	INO(off) INC(off)	V+ = 2.2 V VNO, VNC = 0.5 V / 1.5 V, VCOM = 1.5 V / 0.5 V	Room	-0.5	-	0.5	nA	
			Full	-5	-	5		
	ICOM(off)		Room	-0.5	-	0.5		
			Full	-5	-	5		
Channel-on leakage current ^g	ICOM(on)	V+ = 2.2 V VNO, VNC = VCOM = 0.5 V / 1.5 V	Room	-0.5	-	0.5		
			Full	-5	-	5		
Digital Control								
Input high voltage	VINH		Full	1.6	-	-	V	
Input low voltage	VINL		Full	-	-	0.4		
Input capacitance	CIN		Full	-	3	-	pF	
Input current	IINL or IINH	VIN = 0 V or V+	Full	-1	-	1	μA	
Dynamic Characteristics								
Turn-on time	tON	VNO or VNC = 1.5 V, RL = 300 Ω, CL = 35 pF	Room	-	36	51	ns	
			Full	-	-	62		
Turn-off time	tOFF		Room	-	16	40		
			Full	-	-	43		
Break-before-make time	tđ		Room	1	16	-		
Charge injection ^d	QINJ		CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω	Room	-	21	-	pC
Off-isolation ^d	OIRR		RL = 50 Ω, CL = 5 pF, f = 1 MHz	Room	-	-63	-	dB
Crosstalk ^d	XTALK			Room	-	-63	-	
NO, NC off capacitance ^d	CNO(off) CNC(off)	VIN = 0 V or V+, f = 1 MHz	Room	-	16	-	pF	
Channel-on capacitance ^d	CON		Room	-	52	-		
Power Supply								
Power supply current	I+	VIN = 0 V or V+	Full	-	0.00001	1	μA	

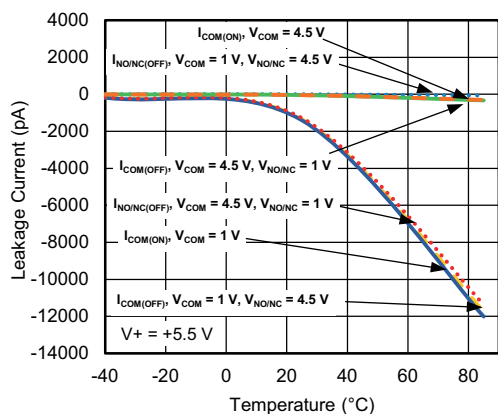
Notes

- Room = 25 °C, full = as determined by the operating suffix
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
- Typical values are for design aid only, not guaranteed nor subject to production testing
- Guarantee by design, nor subjected to production test
- V_{IN} = input voltage to perform proper function
- Guaranteed by 5 V leakage testing, not production tested

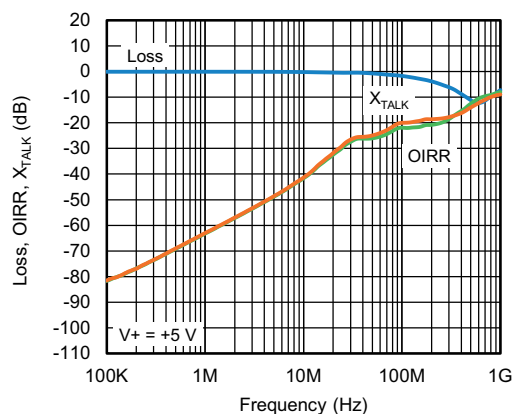
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

 $R_{DS(on)}$ vs. V_{COM} and Supply Voltage

 $R_{DS(on)}$ vs. V_{COM} and Temperature

 $R_{DS(on)}$ vs. V_{COM} and Temperature

Leakage Current vs. Temperature

 $R_{DS(on)}$ vs. V_{COM} and Temperature

Leakage Current vs. Temperature



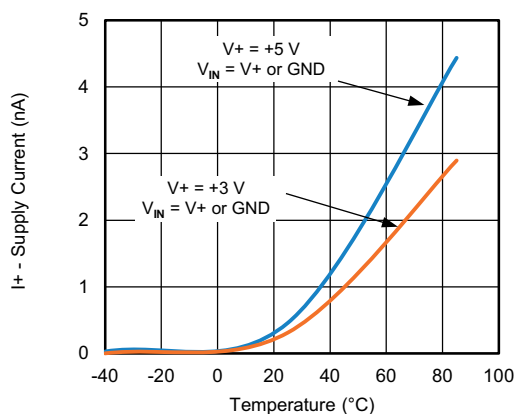
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



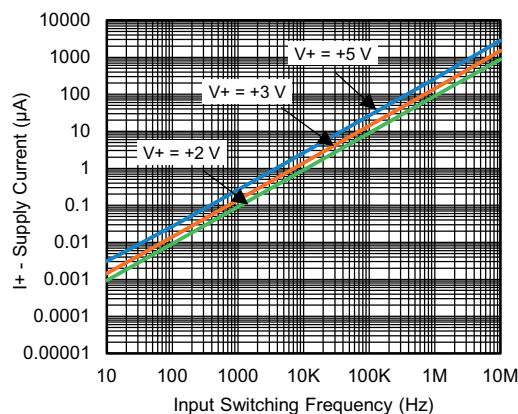
Leakage Current vs. Temperature



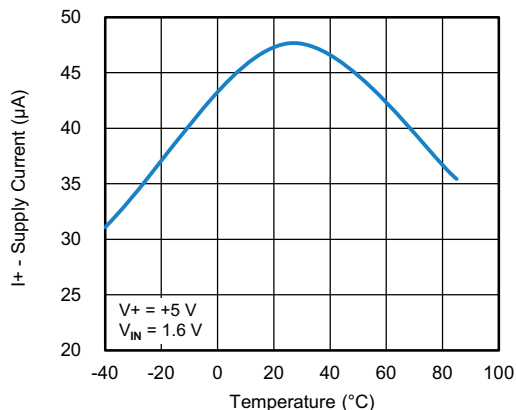
Insertion Loss, Off-Isolation Crosstalk vs. Frequency



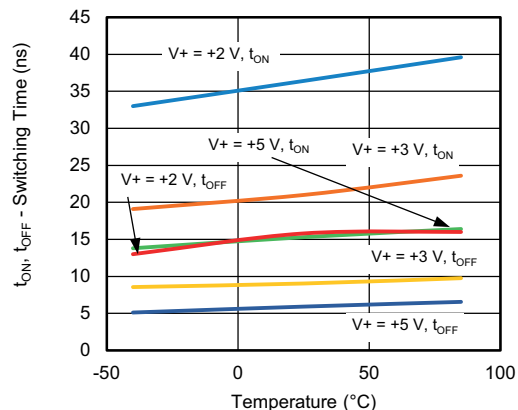
Supply Current vs. Temperature



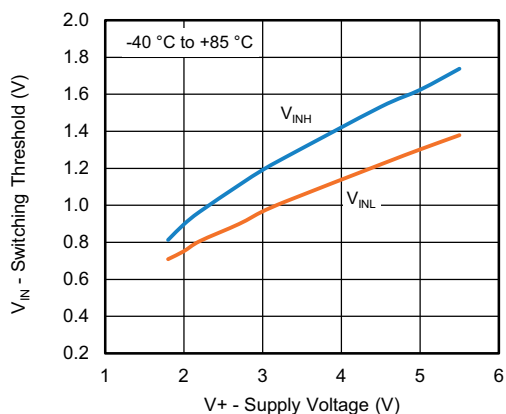
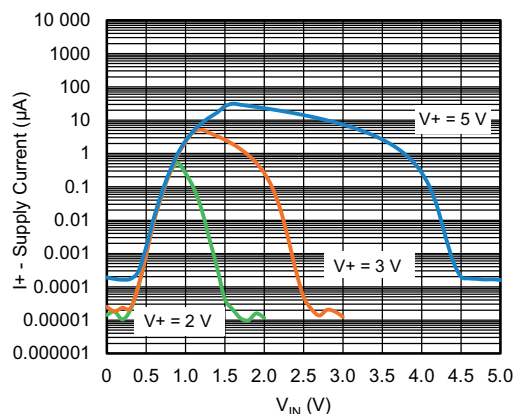
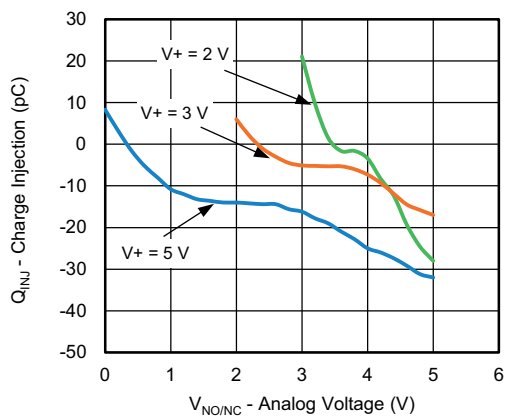
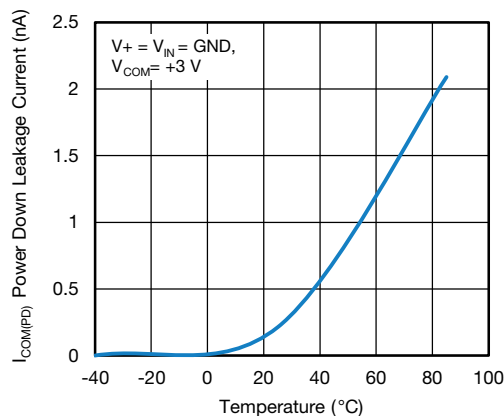
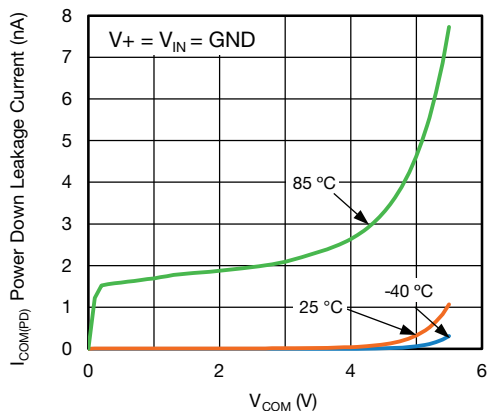
Supply Current vs. Input Switching Frequency

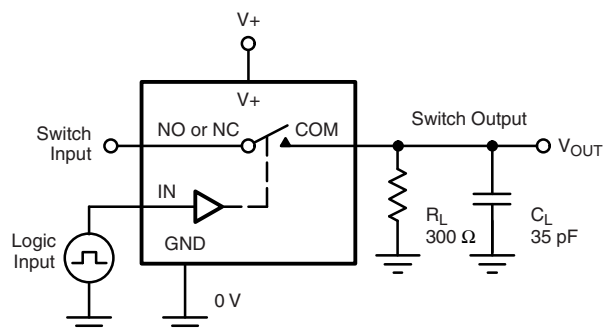


Supply Current vs. Temperature

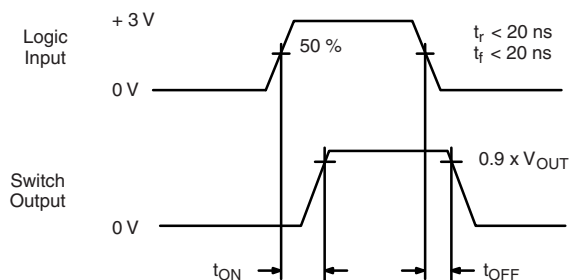


Switching Time vs. Temperature and Supply Voltage

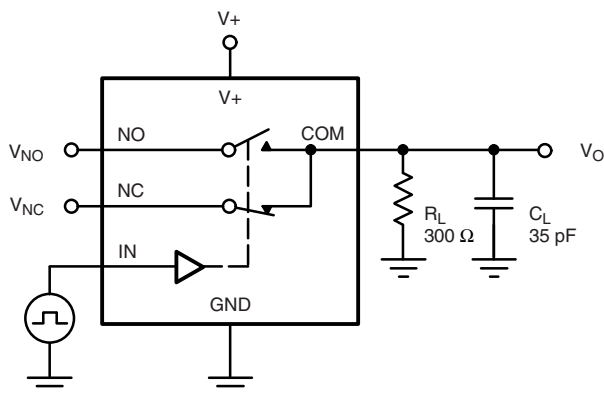
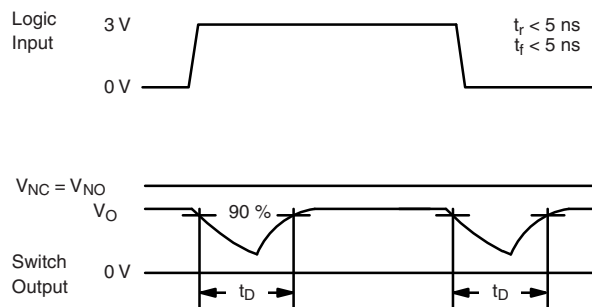
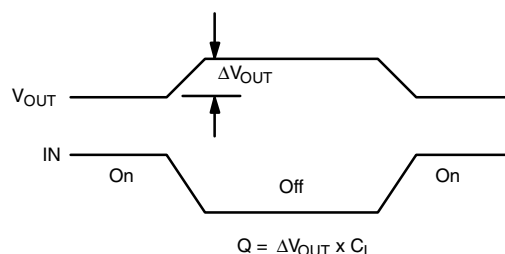
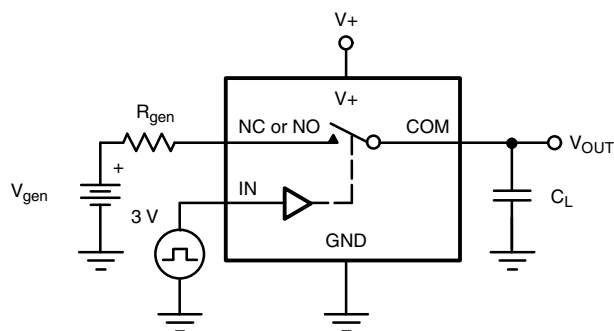
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Switching Threshold vs. Supply Voltage

Supply Current vs. Enable Input Voltage

Charge Injection vs. Analog Voltage

Power Down Leakage Current vs. Temperature

Power Down Leakage Current vs. V_{COM}

TEST CIRCUITS

 C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$

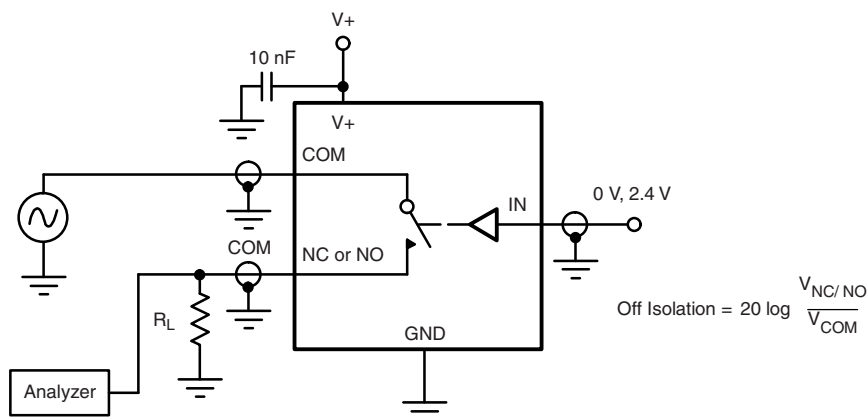
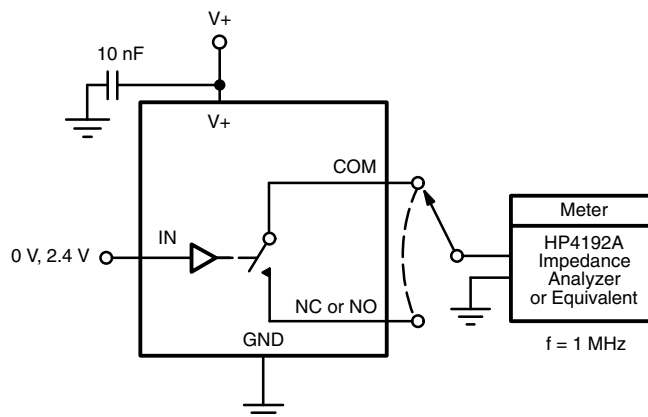


Logic "1" = Switch On
Logic input waveforms inverted for switches that have the opposite logic sense.

Fig. 1 - Switching Time

 C_L (includes fixture and stray capacitance)

Fig. 2 - Break-Before-Make Interval


IN depends on switch configuration: input polarity determined by sense of switch.

Fig. 3 - Charge Injection

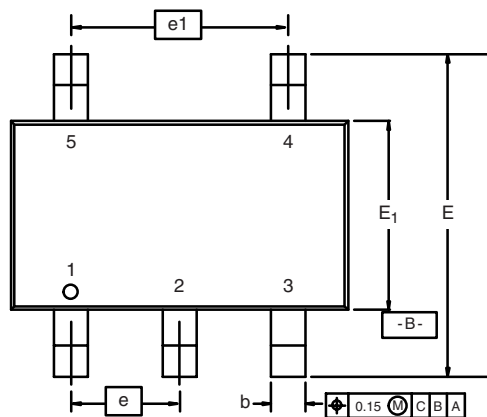
TEST CIRCUITS

Fig. 4 - Off-Isolation

Fig. 5 - Channel Off/On Capacitance

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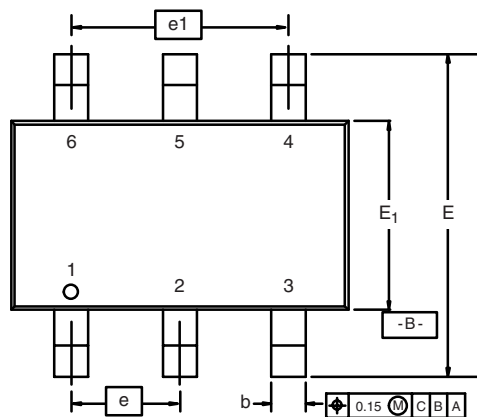


TSOP: 5/6-LEAD

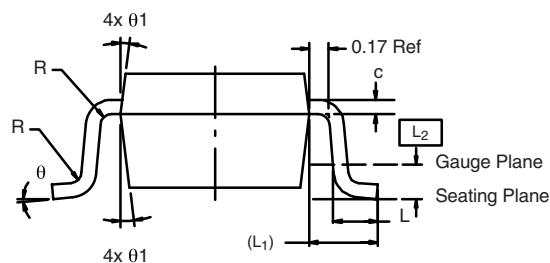
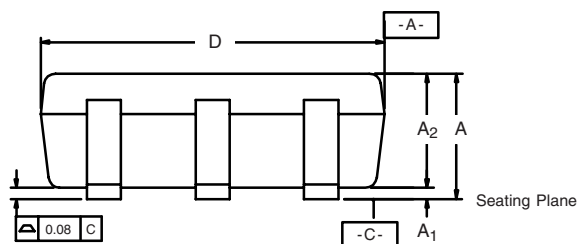
JEDEC Part Number: MO-193C



5-LEAD TSOP

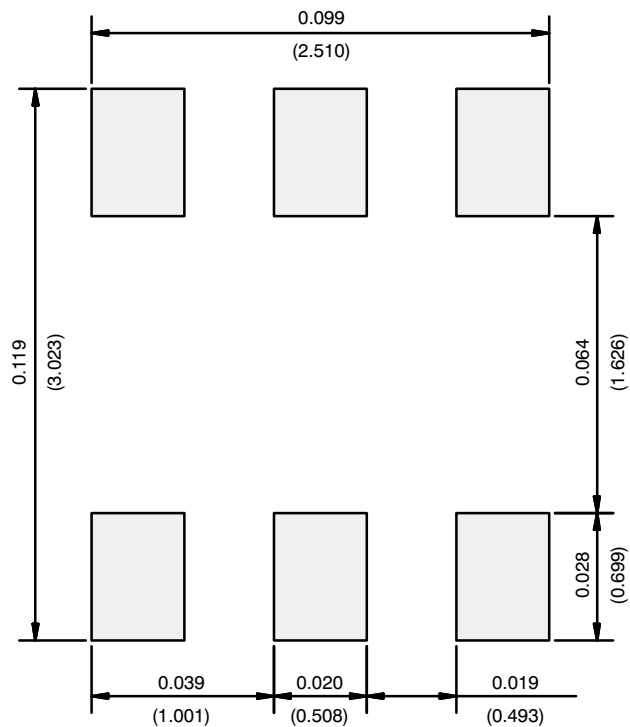


6-LEAD TSOP



	MILLIMETERS			INCHES		
Dim	Min	Nom	Max	Min	Nom	Max
A	0.91	-	1.10	0.036	-	0.043
A ₁	0.01	-	0.10	0.0004	-	0.004
A ₂	0.90	-	1.00	0.035	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
c	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
E	2.70	2.85	2.98	0.106	0.112	0.117
E ₁	1.55	1.65	1.70	0.061	0.065	0.067
e	0.95 BSC			0.0374 BSC		
e ₁	1.80	1.90	2.00	0.071	0.075	0.079
L	0.32	-	0.50	0.012	-	0.020
L ₁	0.60 Ref			0.024 Ref		
L ₂	0.25 BSC			0.010 BSC		
R	0.10	-	-	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
θ ₁	7° Nom			7° Nom		
ECN: C-06593-Rev. I, 18-Dec-06						
DWG: 5540						

RECOMMENDED MINIMUM PADS FOR TSOP-6



Recommended Minimum Pads
Dimensions in Inches/(mm)

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